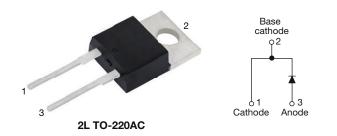
Vishay Semiconductors

www.vishay.com

Ultrafast Rectifier, 15 A FRED Pt[®]



PRIMARY CHARACTERISTICS					
I _{F(AV)} 15 A					
V _R	600 V				
V _F at I _F	0.85 V				
t _{rr} (typ.)	60 ns				
T _J max.	175 °C				
Package	2L TO-220AC				
Circuit configuration	Single				

FEATURES

- · State of the art low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- Low leakage current
- True 2 pin package
- Designed and gualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

State of the art, ultralow V_F, soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM}		600	V			
Average rectified forward current in DC	I _{F(AV)}	T _C = 157 °C	15	٨			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	200	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R			-	-		
Forward voltage V		V _F I _F = 15 A		0.99	1.07	V	
Forward voltage	۷F	I _F = 15 A, T _J = 150 °C	-	0.85	0.91		
		$V_{R} = V_{R}$ rated	-	0.01	15		
Reverse leakage current I_R $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$		-	6	100	μA		
Junction capacitance	CT	V _R = 600 V	-	12	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

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RoHS COMPLIANT HALOGEN



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	CONDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 1$	00 A/µs, V _R = 30 V	-	60	110		
Reverse recovery time	t _{rr}	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 1000 $	100 A/µs, V _R = 30 V	-	185	270	ns	
neverse recovery time		T _J = 25 °C	$ \begin{array}{c c} 5 \ ^{\circ}C & \\ \hline \circ C & \\ 5 \ ^{\circ}C & \\ \circ C & \\ \hline \circ C & \\ \hline \circ C & \\ \end{array} \begin{array}{c c} I_F = 15 \ A, \\ dI_F/dt = 200 \ A/\mu s, \\ V_R = 390 \ V & \\ \hline - & \\ \hline 2 & \\ \hline \end{array} \right) $	-	210	-	115	
		T _J = 125 °C		-	290	-		
Peak recovery current	1	T _J = 25 °C		-	20	-	А	
Feak recovery current	IRRM	T _J = 125 °C		-	26	-	A .	
Reverse recovery charge	0	T _J = 25 °C		-	2.2	-	μC	
	Q _{rr}	T _J = 125 °C		4.0	-	μΟ		

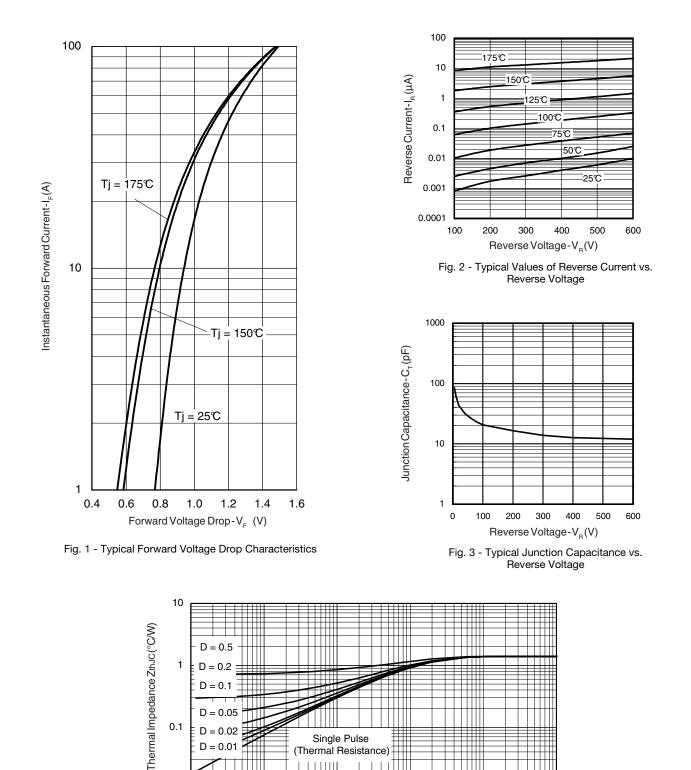
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance, junction-to-case	R _{thJC}		-	1.2	1.4			
Thermal resistance, junction-to-ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W		
Typical thermal resistance, case-to-heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	2	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style 2L TO-220AC		ETL	1506			

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VS-ETL1506-M3

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t1, Rectangular Pulse Duration (Seconds) Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

1E-02

1E-01

1E+00

(Thermal Resistance)

1E-03

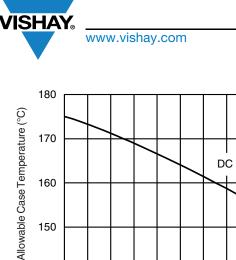
D = 0.01

1E-04

0.01 1E-05



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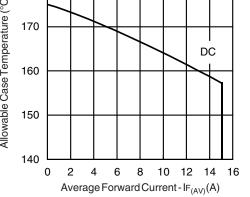


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

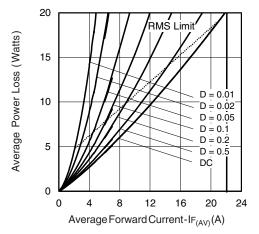
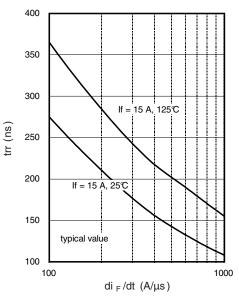


Fig. 6 - Forward Power Loss Characteristics





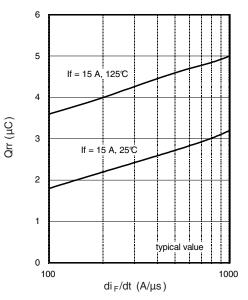


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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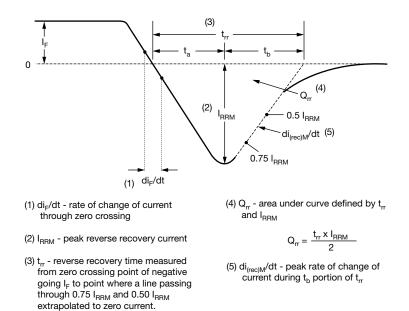


Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	vs-	Е	т	L	15	06	-M3
	1	2	3	4	5	6	7
	1 - 2 -		-	niconduc	•	oduct	
			single	0			
	3 -		2L TO-2	220AC			
	4 -	L =	hyperfa	st recov	ery time	;	
	5 -	Cur	rent cod	le: 15 =	15 A		
	6 -	Volt	age coc	le: 06 =	600 V		
	7 -	Env	ironmer	ntal digit	:		
		-M3	s = halog	gen-free	, RoHS-	-complia	ant, and

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-ETL1506-M3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96156				
Part marking information	www.vishay.com/doc?95391				

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terminations lead (Pb)-free

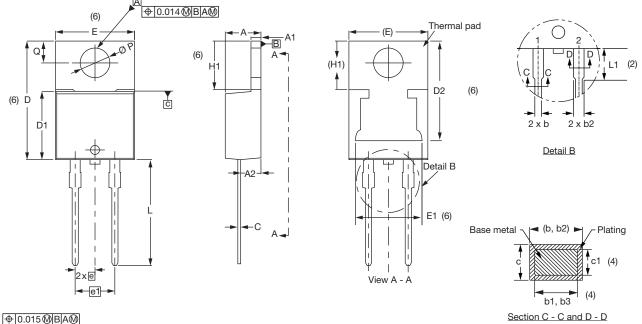
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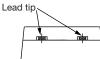


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2L TO-220AC

DIMENSIONS in millimeters and inches





SAMBOI	SYMBOL MILLIMETERS INCHES		HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC®	outline	TO-220AC
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SYMBOL	MILLIN	IETERS	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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